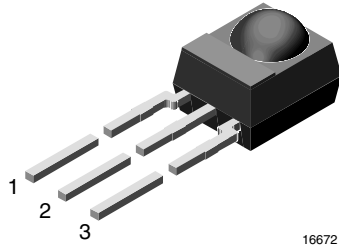


IR Receiver Modules for Remote Control Systems



16672

MECHANICAL DATA

Pinning:

1 = OUT, 2 = V_S , 3 = GND

FEATURES

- Very low supply current
- Photo detector and preamplifier in one package
- Internal filter for PCM frequency
- Improved shielding against EMI
- Supply voltage: 2.5 V to 5.5 V
- Improved immunity against ambient light
- Insensitive to supply voltage ripple and noise
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



DESCRIPTION

The TSOP322.., TSOP324.. series are miniaturized receivers for infrared remote control systems. A PIN diode and a preamplifier are assembled on a lead frame, the epoxy package acts as an IR filter.

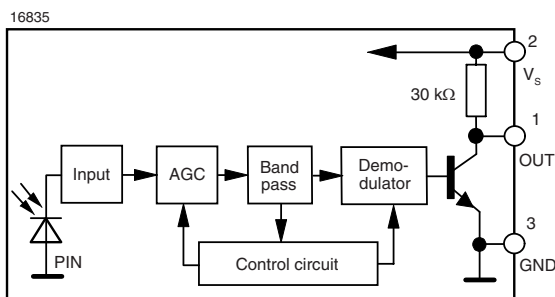
The demodulated output signal can be directly decoded by a microprocessor. The TSOP322.. is compatible with all common IR remote control data formats. The TSOP324.. is optimized to suppress almost all spurious pulses from energy saving fluorescent lamps but will also suppress some data signals.

This component has not been qualified according to automotive specifications.

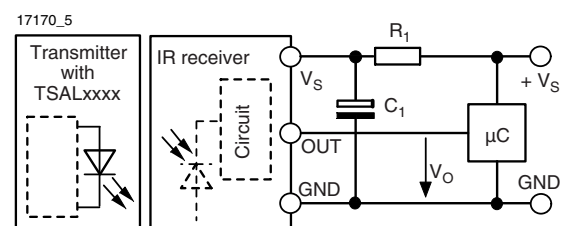
PARTS TABLE

CARRIER FREQUENCY	STANDARD APPLICATIONS (AGC2/AGC8)	VERY NOISY ENVIRONMENTS (AGC4)
30 kHz	TSOP32230	TSOP32430
33 kHz	TSOP32233	TSOP32433
36 kHz	TSOP32236	TSOP32436
38 kHz	TSOP32238	TSOP32438
40 kHz	TSOP32240	TSOP32440
56 kHz	TSOP32256	TSOP32456

BLOCK DIAGRAM



APPLICATION CIRCUIT



R_1 and C_1 are recommended for protection against EOS. Components should be in the range of $33 \Omega < R_1 < 1 \text{ k}\Omega$, $C_1 > 0.1 \mu\text{F}$.

ABSOLUTE MAXIMUM RATINGS (1)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Supply voltage (pin 2)		V_S	- 0.3 to + 6.0	V
Supply current (pin 2)		I_S	3	mA
Output voltage (pin 1)		V_O	- 0.3 to ($V_S + 0.3$)	V
Output current (pin 1)		I_O	5	mA
Junction temperature		T_j	100	°C
Storage temperature range		T_{stg}	- 25 to + 85	°C
Operating temperature range		T_{amb}	- 25 to + 85	°C
Power consumption	$T_{amb} \leq 85$ °C	P_{tot}	10	mW
Soldering temperature	$t \leq 10$ s, 1 mm from case	T_{sd}	260	°C

Note

(1) Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect the device reliability.

ELECTRICAL AND OPTICAL CHARACTERISTICS (1)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Supply current (pin 2)	$E_v = 0, V_S = 3.3$ V	I_{SD}	0.27	0.35	0.45	mA
	$E_v = 40$ klx, sunlight	I_{SH}		0.45		mA
Supply voltage		V_S	2.5		5.5	V
Transmission distance	$E_v = 0$, test signal see fig. 1, IR diode TSAL6200, $I_F = 250$ mA	d		45		m
Output voltage low (pin 1)	$I_{OSL} = 0.5$ mA, $E_e = 0.7$ mW/m ² , test signal see fig. 1	V_{OSL}			100	mV
Minimum irradiance	Pulse width tolerance: $t_{pi} - 5/f_0 < t_{po} < t_{pi} + 6/f_0$, test signal see fig. 1	E_e min.		0.1	0.25	mW/m ²
Maximum irradiance	$t_{pi} - 5/f_0 < t_{po} < t_{pi} + 6/f_0$, test signal see fig. 1	E_e max.	30			W/m ²
Directivity	Angle of half transmission distance	$\phi_{1/2}$		± 45		deg

Note

(1) $T_{amb} = 25$ °C, unless otherwise specified

TYPICAL CHARACTERISTICS

$T_{amb} = 25$ °C, unless otherwise specified

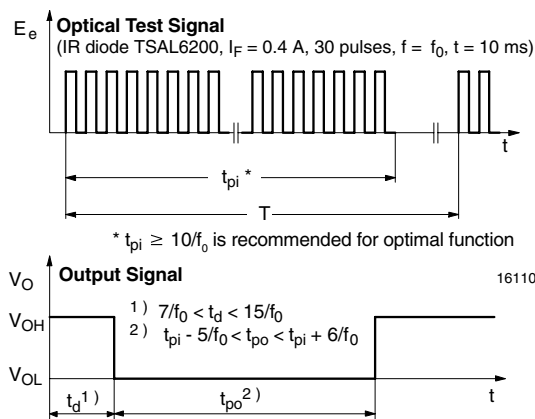


Fig. 1 - Output Active Low



Fig. 2 - Pulse Length and Sensitivity in Dark Ambient



Fig. 3 - Output Function



Fig. 6 - Sensitivity in Bright Ambient



Fig. 4 - Output Pulse Diagram

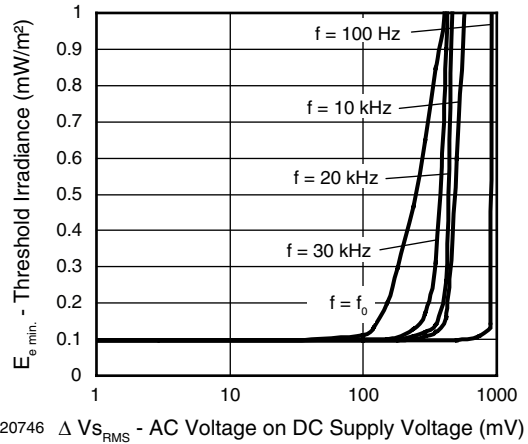


Fig. 7 - Sensitivity vs. Supply Voltage Disturbances



Fig. 5 - Frequency Dependence of Responsivity



Fig. 8 - Sensitivity vs. Electric Field Disturbances

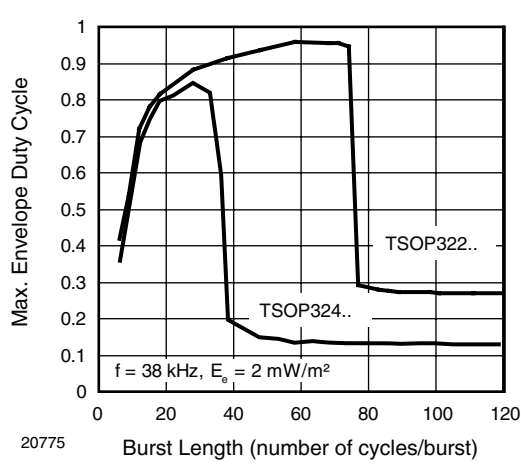


Fig. 9 - Maximum Envelope Duty Cycle vs. Burst Length



Fig. 12 - Horizontal Directivity

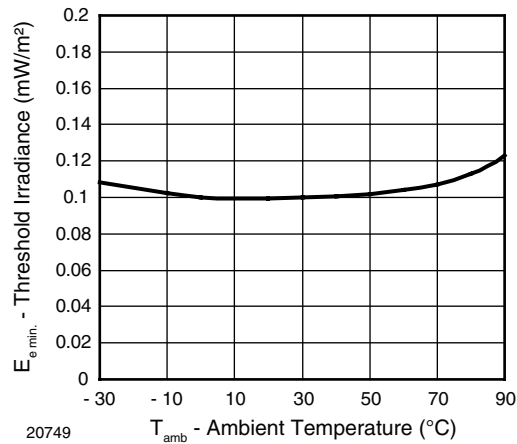


Fig. 10 - Sensitivity vs. Ambient Temperature



Fig. 13 - Sensitivity vs. Supply Voltage



Fig. 11 - Relative Spectral Sensitivity vs. Wavelength

SUITABLE DATA FORMAT

The TSOP322.., TSOP324.. series are designed to suppress spurious output pulses due to noise or disturbance signals. Data and disturbance signals can be distinguished by the devices according to carrier frequency, burst length and envelope duty cycle. The data signal should be close to the band-pass center frequency (e.g. 38 kHz) and fulfill the conditions in the table below.

When a data signal is applied to the TSOP322.., TSOP324.. in the presence of a disturbance signal, the sensitivity of the receiver is reduced to insure that no spurious pulses are present at the output. Some examples of disturbance signals which are suppressed are:

- DC light (e.g. from tungsten bulb or sunlight)
- Continuous signals at any frequency
- Strongly or weakly modulated noise from fluorescent lamps with electronic ballasts (see figure 14 or figure 15)



Fig. 14 - IR Signal from Fluorescent Lamp with Low Modulation



Fig. 15 - IR Signal from Fluorescent Lamp with High Modulation

	TSOP322..	TSOP324..
Minimum burst length	10 cycles/burst	10 cycles/burst
After each burst of length a minimum gap time is required of	10 to 70 cycles ≥ 10 cycles	10 to 35 cycles ≥ 10 cycles
For bursts greater than a minimum gap time in the data stream is needed of	70 cycles > 4 x burst length	35 cycles > 10 x burst length
Maximum number of continuous short bursts/second	1800	1500
Compatible to NEC code	yes	yes
Compatible to RC5/RC6 code	yes	yes
Compatible to Sony code	yes	no
Compatible to Thomson 56 kHz code	yes	yes
Compatible to Mitsubishi code (38 kHz, preburst 8 ms, 16 bit)	yes	no
Compatible to Sharp code	yes	yes
Suppression of interference from fluorescent lamps	Most common disturbance signals are suppressed	Even extreme disturbance signals are suppressed

Note

For data formats with short bursts please see the datasheet for TSOP321.., TSOP323..

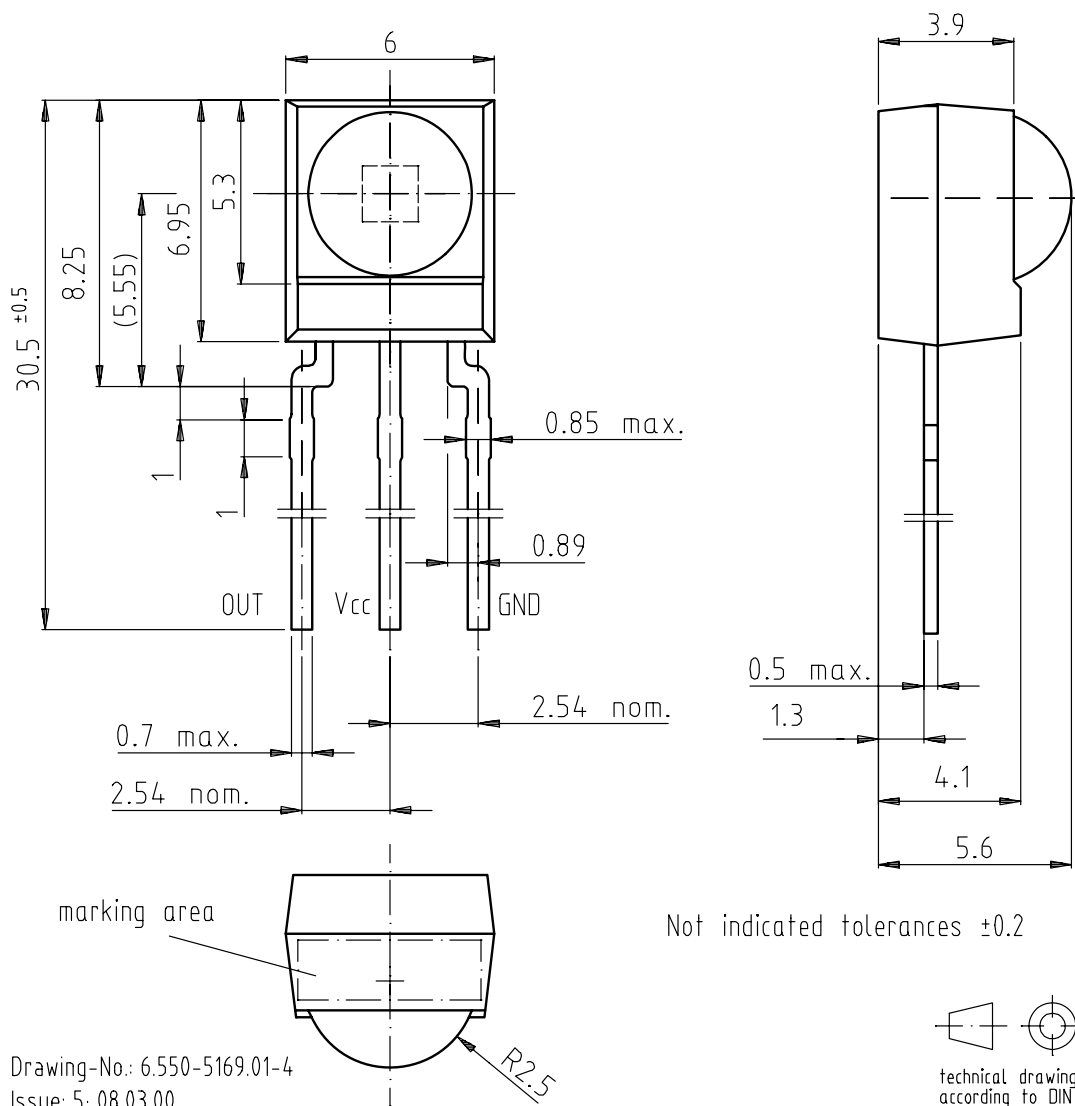
TSOP322.., TSOP324..

Vishay Semiconductors

IR Receiver Modules for
Remote Control Systems



PACKAGE DIMENSIONS in millimeters



Drawing-No.: 6.550-5169.01-4
Issue: 5; 08.03.00

13655

technical drawings
according to DIN
specifications

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2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

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